

UNISONIC TECHNOLOGIES CO., LTD

6N60K-TA **Preliminary Power MOSFET**

6.2A, 600V N-CHANNEL POWER MOSFET

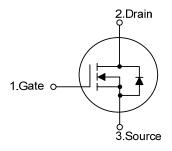
DESCRIPTION

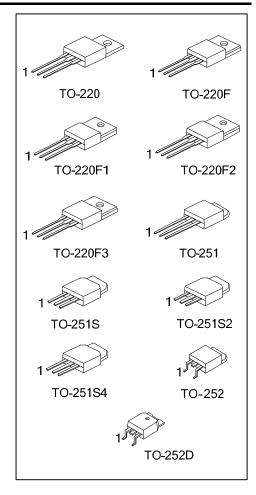
The UTC 6N60K-TA is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in switching power supplies and adaptors.

FEATURES

- * $R_{DS(ON)}$ < 1.40 @ V_{GS} = 10V, I_{D} = 3.1A
- * Fast switching capability
- * Avalanche energy tested
- * Improved dv/dt capability, high ruggedness

SYMBOL

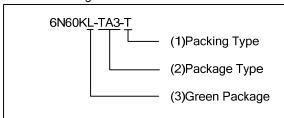




■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2 3		Packing	
6N60KL-TA3-T	6N60KG-TA3-T	TO-220	G	D	D S Tube		
6N60KL-TF3-T	6N60KG-TF3-T	TO-220F	G	D	S	Tube	
6N60KL-TF1-T	6N60KG-TF1-T	TO-220F1	G	D	S	Tube	
6N60KL-TF2-T	6N60KG-TF2-T	TO-220F2	G	D	S	Tube	
6N60KL-TF3-T	6N60KG-TF3-T	TO-220F3	G	D	S	Tube	
6N60KL-TM3-T	6N60KG-TM3-T	TO-251	G	D	S	Tube	
6N60KL-TMS-T	6N60KG-TMS-T	TO-251S	G	D	S	Tube	
6N60KL-TMS2-T	6N60KG-TMS2-T	TO-251S2	G	D	S	Tube	
6N60KL-TMS4-T	6N60KG-TMS4-T	TO-251S4	G	D	S	Tube	
6N60KL-TN3-R	6N60KG-TN3-R	TO-252	G	D	S	Tape Reel	
6N60KL-TND-R	6N60KG-TND-R	TO-252D	G	D	S	Tape Reel	

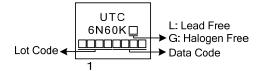
Note: Pin Assignment: G: Gate D: Drain S: Source



- (1) T: Tube, R: Tape Reel
- (2) TA3: TO-220, TF3: TO-220F, TF1: TO-220F1, TF2: TO-220F2, TF3: TO-220F3, TM3: TO-251 TMS: TO-251S, TMS2: TO-251S2,

TMS4: TO-251S4, TN3: TO-252, TND: TO-252D (3) L: Lead Free, G: Halogen Free and Lead Free

■ MARKING



■ **ABSOLUTE MAXIMUM RATINGS** (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	600	V
Gate-Source Voltage		V_{GSS}	±30	V
Avalanche Current (Note 2)		I _{AR}	6.2	Α
Continuous Drain Current		I_{D}	6.2	Α
Pulsed Drain Current (Note 2)		I _{DM}	I _{DM} 24.8	
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	260	mJ
	Repetitive (Note 2)	E _{AR}	13	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	ns
Power Dissipation	TO-220		125	W
	TO-220F/TO-220F1 TO-220F3		40	W
	TO-220F2	P_{D}	42	W
	TO-251/TO-251S TO-251S2/TO-251S4 TO-252/TO-252D		55	W
Junction Temperature		TJ	+150	°C
Operating Temperature		T _{OPR}	-55 ~ +150	°C
Storage Temperature		T _{STG}	-55 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating : Pulse width limited by T_{J}
- 3. L = 14.4mH, I_{AS} = 6A, V_{DD} = 90V, R_{G} = 25 Ω , Starting T_{J} = 25°C
- 4. $I_{SD} \le 6.2A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F TO-220F1/TO-220F2 TO-220F3	0	62.5	°C/W
	TO-251/TO-251S TO-251S2/TO-251S4 TO-252/TO-252D	$ heta_{ m JA}$	110	°C/W
Junction to Case	TO-220		1.0	°C/W
	TO-220F/TO-220F1 TO-220F3		3.2	°C/W
	TO-220F2	θ_{JC}	2.97	°C/W
	TO-251/TO-251S TO-251S2/TO-251S4 TO-252/TO-252D		2.27	°C/W

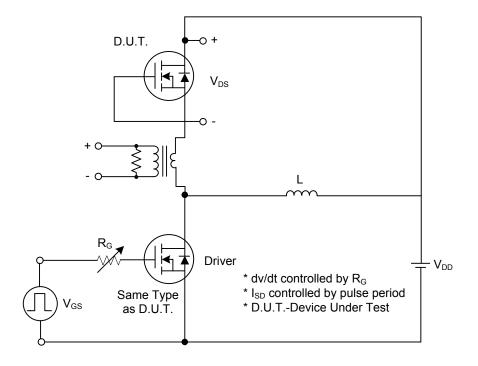
■ **ELECTRICAL CHARACTERISTICS** (T_J =25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V_{GS} =0V, I_D =250 μ A	600			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =600V, V _{GS} =0V			10	μA
			V _{DS} =480V, V _{GS} =0V, T _J =125°C			10	μΑ
Gate- Source Leakage Current	Forward		$V_{G=}30V$, $V_{DS}=0V$			100	nA
	Reverse	I_{GSS}	V_{GS} =-30V, V_{DS} =0V			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS}/\triangle T_{J}$	ΔT_J I _D =250µA, Referenced to 25°C		0.53		V/°C
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	2.5		4.5	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =3.1A			1.4	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C _{ISS}			690		pF
Output Capacitance		Coss	V _{DS} =25V, V _{GS} =0V, f=1.0 MHz		85		pF
Reverse Transfer Capacitance		C _{RSS}			17		pF
SWITCHING CHARACTERISTICS	S						
Turn-On Delay Time		t _{D(ON)}			60		ns
Turn-On Rise Time		t _R	V_{DD} =30V, I_{D} =0.5A, R_{G} =25 Ω		60		ns
Turn-Off Delay Time		t _{D(OFF)}	(Note 1, 2)		120		ns
Turn-Off Fall Time		t_{F}			50		ns
Total Gate Charge		Q_G	\\ -E0\\ =1.24 \\ -10\\		21	25	nC
Gate-Source Charge		Q_GS	V _{DS} =50V, I _D =1.3A, V _{GS} =10V (Note 1, 2)		6		nC
Gate-Drain Charge		Q_GD	(Note 1, 2)		4.5		nC
DRAIN-SOURCE DIODE CHARA	CTERISTIC	CS AND MAXII	MUM RATINGS				
Drain-Source Diode Forward Voltage		V_{SD}	V _{GS} =0V, I _S =6.2 A			1.4	V
Maximum Continuous Drain-Source Diode		I _S				6.2	A
Forward Current						0.2	A
Maximum Pulsed Drain-Source Diode		I _{SM}				24.8	A
Forward Current						24.0	^

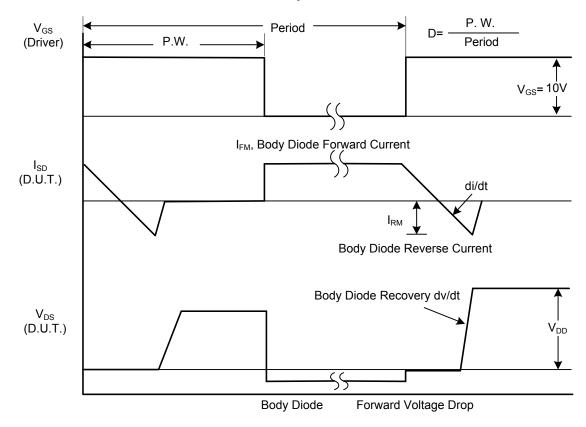
Notes: 1. Pulse Test: Pulse width \leq 300 μ s, Duty cycle \leq 2%.

^{2.} Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

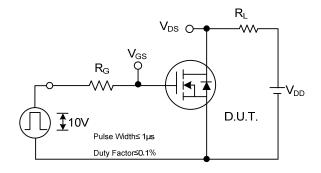


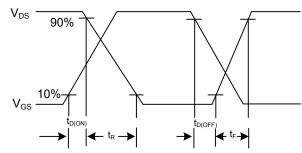
Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

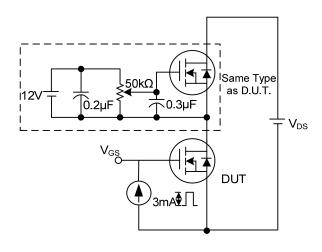
■ TEST CIRCUITS AND WAVEFORMS (Cont.)

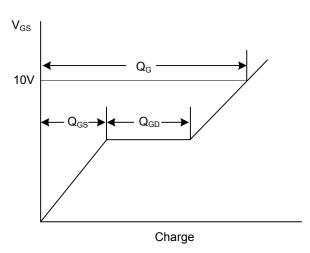




Switching Test Circuit

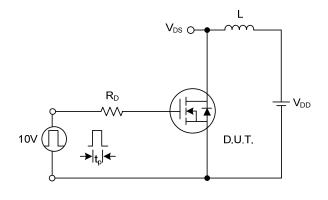
Switching Waveforms

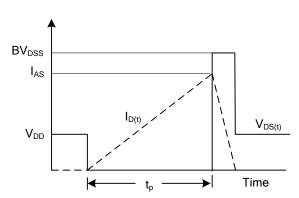




Gate Charge Test Circuit

Gate Charge Waveform





Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

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